EAST Search History

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	252028	power near2 (layer wire line)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 17:21
L6	60	(349/149-152.ccls. 257/72. ccls.) and (Ig hynix samsung).as. and L5	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 17:21
S40	104	349/140.ccls.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:27
S41	3294	257/72.cdls.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:45
S42	249398	power near2 (layer wire line)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:49
S43	337322	(gate scan scanning) near2 (line wire layer)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:51
S44	732364	(signal data) near2 (wire line layer)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:52
S45	140038	tft or "thin film transistor" or (thin near film near transistor)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:52
S47	5254	S42 and S43 and S44 and S45 and capacitor	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:53

S48	76089	S44 with (source drain)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:54
S49	4016	S48 and S47	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 20:54
S50	152713	(anode pixel cathode) near (electrode layer)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 21:01
S51	8440	S42 with (source drain) with (contact hole via)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 21:17
S52	495	S51 and S43 and S44 and S45 and @ad<="20040127"	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 21:18
S53	30	S51 and S43 and S44 and S45 and @ad<="20040127" and (S42 with S44 with (another different))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/11 21:19
S54	1668	grid near7 ((power supply) near2 (line wire layer))	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/09 17:25
S55	146348	TFT "thin film transistor" (thin near2 transistor)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/09 17:25
S56	154241	(anode pixel cathode) near (electrode layer)	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/09 17:25
S57	26	S54 and S55 and S56	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/09 17:25

S58	12	S54 and S55 and S56 and	US-PGPUB;	OR	ON	2009/04/09	
		@ad<="20040127"	USPAT; FPRS;			17:35	
			EPO; JPO;				
			DERWENT;				-
			IBM_TDB				

4/12/2009 7:50:21 PM

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